

Form PTO 1449
(Modified)U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICE

ATTY DOCKET NO.

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SERIAL NO.

New A, 01/09/97

LIST OF REFERENCES CITED BY APPLICANT

APPLICANT

Yuuichi HIRANO, et al.

FILING DATE

Herewith

GROUP

U.S. PATENT DOCUMENTS

| EXAMINER INITIAL | | DOCUMENT NUMBER | DATE | NAME | CLASS | SUB CLASS | FILING DATE IF APPROPRIATE |
|---------------------|----|--------------------|------|------|-------|--------------|-------------------------------|
| | AA | | | | | | |
| | AB | | | | | | |
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| | AL | | | | | | |
| | AM | | | | | | |
| | AN | | | | | | |

FOREIGN PATENT DOCUMENTS

| | | DOCUMENT NUMBER | DATE | COUNTRY | TRANSLATION YES | NO |
|------|----|--------------------|----------|-------------------------------|--------------------|----|
| VAMS | AO | 3-156929 | 07/04/91 | JAPAN (with English abstract) | | X |
| VAMS | AP | 6-130304 | 05/21/96 | JAPAN (with English abstract) | | X |
| | AQ | | | | | |
| | AR | | | | | |
| | AS | | | | | |
| | AT | | | | | |
| | AU | | | | | |
| | AV | | | | | |

OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.)

| | | |
|------|----|---|
| VAMS | AW | K. IMAI, et al.; "A 0.13- μ m CMOS TECHNOLOGY INTEGRATING HIGH-SPEED AND LOW-POWER/HIGH-DENSITY DEVICES WITH TWO DIFFERENT WELL/CHANNEL STRUCTURES"; IEEE IEDM, 1999, pgs. 667-670. |
| | AX | |
| | AY | |
| | AZ | |

Examiner

Victor A. Mandala g.

Date Considered

11-14-02

*Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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